



Low power Hall switch SDC1217

Overview

SDC1217 is a high-precision, low-power Hall switch for unipolar magnetic field detection, giving a corresponding digital output. The typical power consumption is less than 4uW, so it is very suitable for low-power consumption products. For battery-powered systems where power consumption is a priority, such as touch-screen mobile phones, Tablets, laptops, etc.

This product has precise magnetic switch switching points and is Low sensitivity to process variations and temperature changes.

Available in small SOT-23-3, TO-92 and DFN-4L sizes.

Features

- Extremely low power consumption design
 - Operating voltage range: 1.65V~5.5V
 - Output mode: CMOS output
 - Chopper amplifier design, due to process, operating temperature and mechanical stress
 - Low noise and offset sensitivity
 - S/N pole use
 - Package: SOT-23-3, TO-92S, DFN-4L
- application
- Touch-screen mobile phones, tablet computers
 - Laptops, digital cameras
 - Toys , game consoles
 - Household appliances

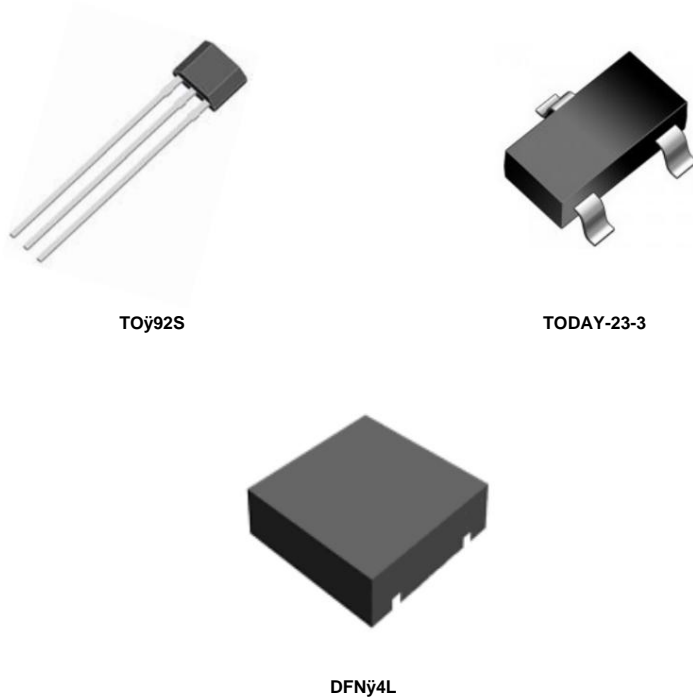
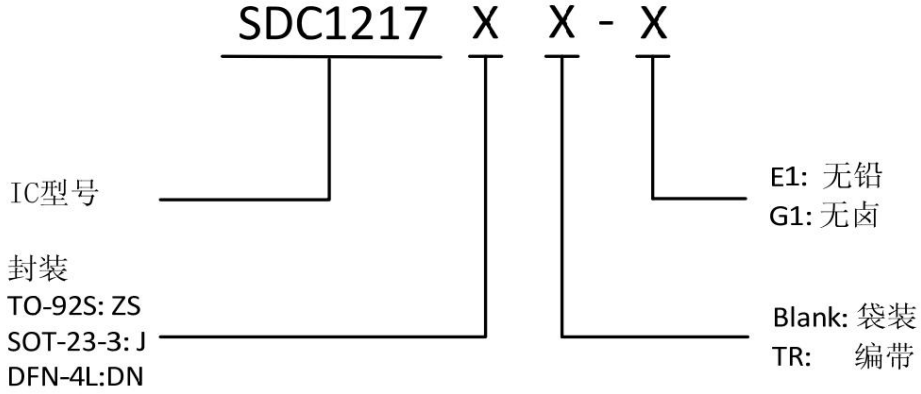


Figure 1. Package type



Low power Hall switch SDC1217

Ordering Information



Package	temperature range	Product Number		Identification number		Packaging
		Lead Free	Halogen Free	Lead Free	Halogen Free	
TO92S	-40°C~125°C	SDC1217ZSÿE1	SDC1217ZSÿG1	1217	1217G Bag	
TODAY-23-3		SDC1217JTRÿE1	SDC1217JTRÿG1	1217	1217G Taping	
DFN4L		SDC1217DNTRÿE1	SDC1217DNTRÿG1	1217	1217G Taping	



Low power Hall switch SDC1217

Limit parameters (Note: Do not exceed the maximum value in application to prevent damage. Long-term operation at the maximum value may affect the reliability of the device)

Parameter Symbols		condition	Parameter Value	unit
Storage Temperature Range	TS	-	-40~150	°C
DC Supply Voltage Supply	VDD	-	1.6~6	V
Current Magnetic	IDD	-	-1.0~2.5	mA
Induction Strength	B	-	No restrictions	°C
Maximum Junction Temperature	TJ	-	150	°C
PIN soldering temperature		10 seconds	<260	°C
ESD,HBM model per Mil-Std-883H, Method 3015	HBM	-	4000	V
ESD,MM model per JEDEC EIA/JESD22-A115	MM	-	400	V
Latch-up test per JEDEC 78		-	200	mA

Table 2. Limit parameters

Recommended operating conditions

parameters	symbol	Minimum	typical	Maximum	unit
Supply voltage range	VDD	1.65	-	5.5	V
Output voltage range	VOUT	-0.3	-	5.5	V
Operating temperature	Facing	-40	25	125	°C

Table 3. Recommended operating conditions



Low power Hall switch SDC1217

Electrical Characteristics (Unless otherwise specified, VDD=3.3V, Ta=25°C)

Parameter Symbol		Test condition	Min	Typ	Max	Unit
static parameters						
Average supply current	IDD			2	4	uA
Operating current	ION			1.5		mA
Standby current	IS			1.5		uA
Output saturation current	VSAT	IOUT=2mA		0.1		V
Output voltage	HAIR	VOUT=5.5V		0.01		uA
Leakage current	tON			50		us
Operating time Standby time	tOFF			90		ms

Table 4. Electrical characteristics

Characteristic curves

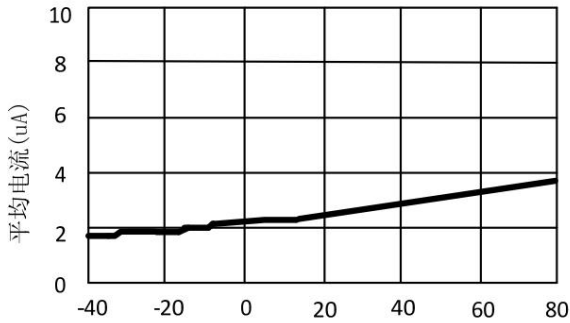


Figure 4. Average current vs. ambient temperature (VDD=3.3V)

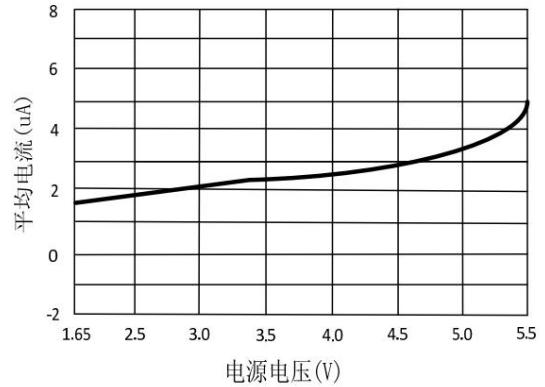


Figure 5. Average current vs. supply voltage (Ta=25°C)



Low power Hall switch SDC1217

Magnetic field characteristics

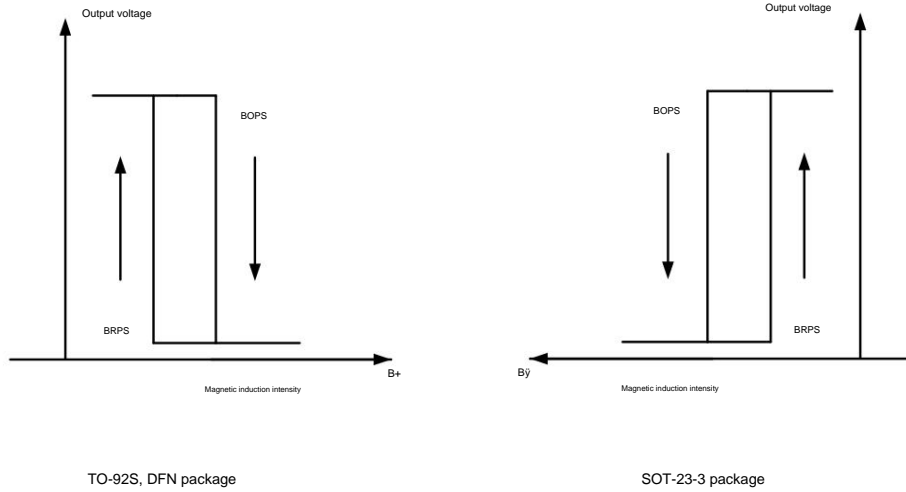


Figure 6. Magnetic field characteristics diagram

Magnetic field reversal point

parameters	symbol	condition	Min	Typ	Max	Unit
Hysteresis	BOP		-		25	30 GS
width of	BRP		10		15	GS
operating point and release point	WHY	$BHYS = BOP - BRP$	-		10	GS



Low power Hall switch SDC1217

How it works

Power-On Reset

This module determines the switching threshold of the Hall switch.

When the power is turned on, the power-on reset circuit immediately resets the digital circuit to bias the circuit

Get proper operation after startup.

Bias circuit provides Hall element, chopper amplifier and hysteresis control

Oscillators and Sequencers

Precise current bias, insensitive to temperature and process variations.

The built-in oscillator provides a clock signal to the timing device to determine the working time.

Correct operation and precise switching points can be guaranteed within the range of environmental changes.

The typical working time is 50us and the standby time is

Chopper Amplifier

90ms. In this timing state, its average power consumption is almost equal to the standby power consumption.

To achieve higher resolution, chopper amplifier is used in the design

It is about 4uW when VDD=1.85V.

It can dynamically remove offsets and interference.

Hysteresis control

Typical application diagram

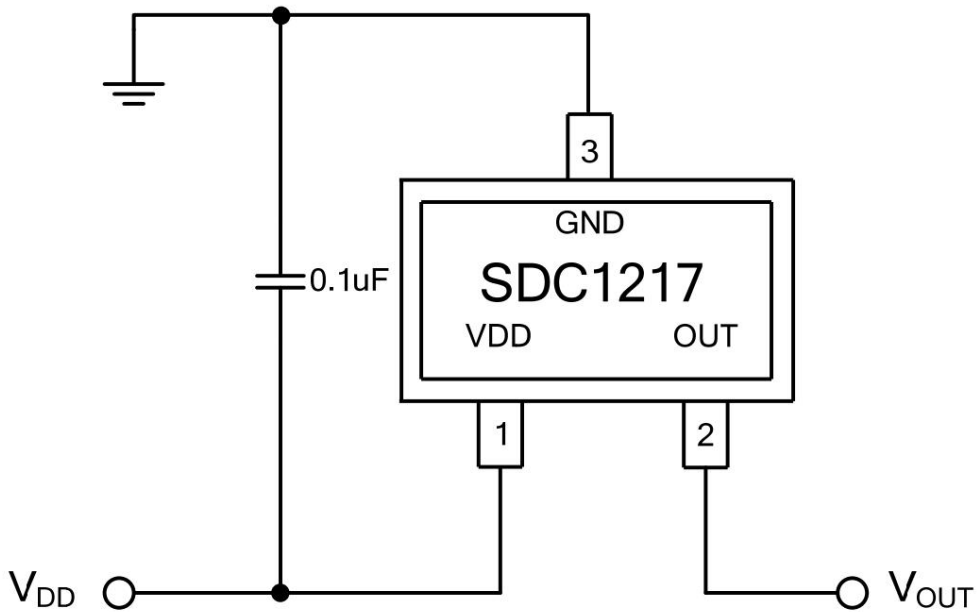


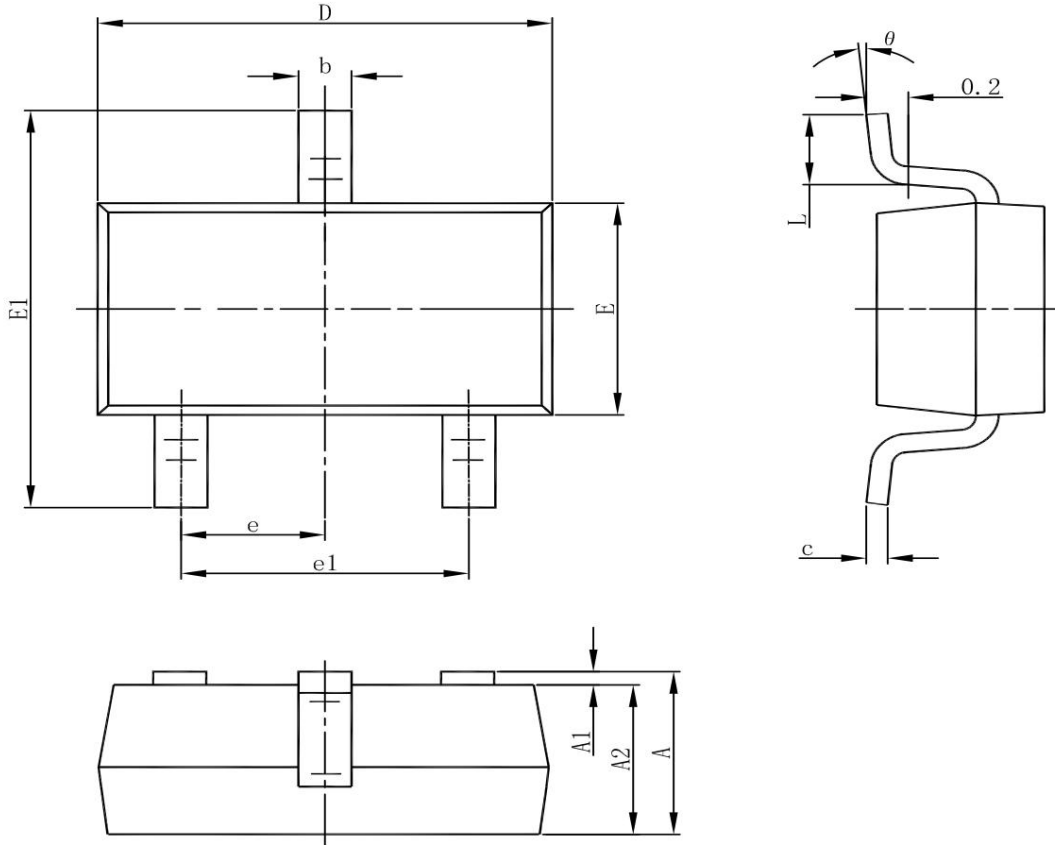
Figure 7. Typical application diagram



Low power Hall switch SDC1217

Package size

TODAY-23-3

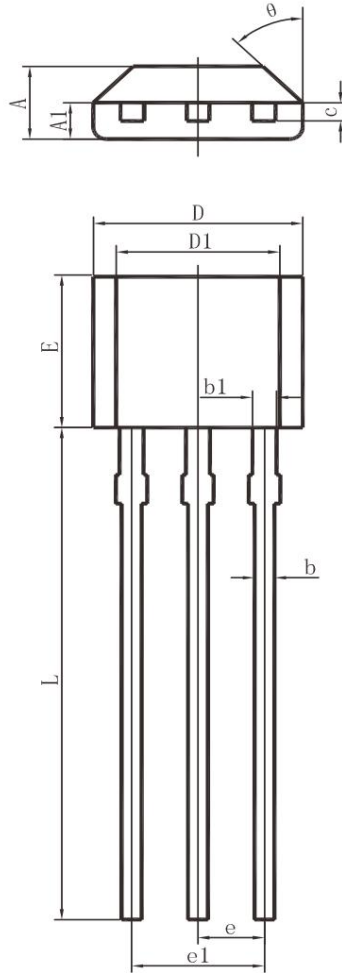


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
e	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
and	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
i	0°	8°	0°	8°



Low power Hall switch SDC1217

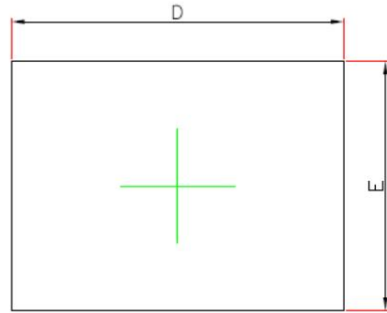
TO92S



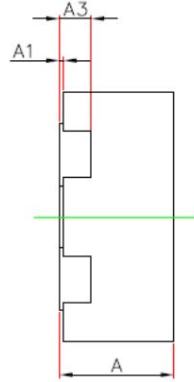
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.420	1.620	0.056	0.064
A1	0.660	0.860	0.026	0.034
b	0.350	0.480	0.014	0.019
b1	0.380	0.530	0.015	0.021
c	0.360	0.510	0.014	0.020
D	3.900	4.100	0.154	0.161
D1	2.970	3.270	0.117	0.129
and	2.900	3.100	0.116	0.124
and	1.270 TYPE.		0.050 TYPE.	
e1	2.440	2.640	0.096	0.104
L	14.500	14.900	0.580	0.596
i	45° TYPE.		45° TYPE.	

Low power Hall switch SDC1217

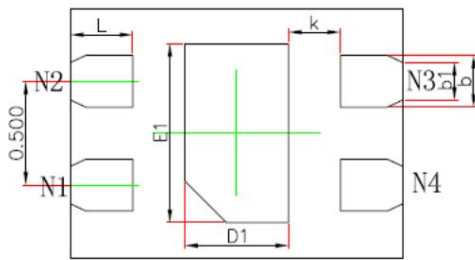
DFN4L



TOP VIEW



SIDE VIEW



BOTTOM VIEW

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN.	MAX.	MIN.	MAX.
A	0.500	0.600	0.020	0.024
A1	0.000	0.050	0.000	0.002
A3	0.152REF.		0.006REF.	
D	1.500	1.700	0.059	0.067
E	1.100	1.300	0.043	0.051
D1	0.400	0.600	0.016	0.024
E1	0.760	0.960	0.030	0.038
b	0.200	0.300	0.008	0.012
b1	0.180REF.		0.007REF.	
e	0.500BSC.		0.020BSC.	
L	0.224	0.376	0.009	0.015
k	0.250REF.		0.010REF.	



Low power Hall switch SDC1217



Shaoxing Everbright Core Industry Microelectronics Co., Ltd.

<http://www.sdc-semi.com>

Important Notice

This document only provides information about the company's products. Shaoxing Everbright Core Industry Microelectronics Co., Ltd. reserves the right to make any changes to the products and services described in this document without prior notice. changes, corrections, modifications and improvements at any time. Shaoxing Everbright Core Industry Microelectronics Co., Ltd. assumes no responsibility for any specific use of the product, nor any Any liability beyond the application or use of the product. Shaoxing Guangda Xinye Microelectronics Co., Ltd. does not establish any license on its patents or other rights.

© 2018 Shaoxing Everbright Core Microelectronics Co., Ltd. All rights reserved

Contact Us:

Shaoxing Head Office

Shenzhen Branch

Address: No. 13 Tianmu Road, Shaoxing City, Zhejiang Province

Address: 22A, Shangbu Building, No. 68, Nanyuan Road, Futian District, Shenzhen

Zip code: 312000

Zip code: 518031

Tel: (86) 0575-8861 6750

Tel: (86) 0755-8366 1155

Fax: (86) 0575-8862 2882

Fax: (86) 0755-8301 8528